

Fabrication and photoactivities of spherical-shaped BiVO_4 photocatalysts through solution combustion synthesis method

Hai-qing Jiang^{*}, Hiromitsu Endo, Hirotaka Natori, Masayuki Nagai, Koichi Kobayashi

Research Center for Energy and Environmental Science, Advance Research Laboratories, Musashi Institute of Technology, Tokyo 158-0082, Japan

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Abstract

Spherical-shaped BiVO_4 photocatalysts were prepared by the solution combustion synthesis method. The as-prepared photocatalysts were characterized by X-ray diffraction (XRD), nitrogen absorption for the BET specific surface area, field emission scanning electron microscopy (FE-SEM) and ultraviolet–visible diffraction reflection spectroscopy (UV–vis). The BiVO_4 crystallites show a monoclinic structure with diameter of about 400–600 nm. UV–vis diffraction absorption spectra indicate that the band gap absorption edge of pure BiVO_4 crystallites prepared by the SCS method and the SSR method are 523 nm and 540 nm, corresponding to the band gap energies of 2.45 eV and 2.40 eV, respectively. It is also found that the photocatalytic activity of degradation of methylene blue improves when the molar ratio of fuels to oxidizer is 5.

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1. Introduction

Bismuth vanadate (BiVO_4) has attracted significant recent attention because of its good ferroelasticity,^{1,2} ionic conductivity,³ and its photocatalytic activity for degradation of organic materials⁴ and organic dyes,^{5–7} as well as for splitting of water for hydrogen⁸ and oxygen evolution.^{9,10} It is known that photocatalytic properties strongly depend on the crystal structure. BiVO_4 powder with a monoclinic structure shows high photocatalytic activity because of its relatively narrow band gap of 2.4 eV, as compared to BiVO_4 with a tetragonal phase (3.1 eV). Recently, various techniques are used to synthesize monoclinic structure BiVO_4 crystallites, such as aqueous process,^{4,9,10} hydrothermal process,^{5,6} sonochemical method,⁷ organic decomposition method,⁸ chemical bath deposition,¹¹ and solid-state reaction (SSR) method.¹²

In the present study, a solution combustion synthesis (SCS) method was used to prepare the BiVO_4 crystallites. The SCS method¹³ has emerged as an important technique for the synthesis and processing of advanced ceramics, catalysts, composites, alloys, intermetallics and nanocrystallites. In particular, the SCS

method of preparing oxide materials is a fairly recent development, and this technique has been used to produce homogeneous and fine crystalline powders.¹⁴ The SCS method takes advantage of exothermic, fast and self-sustaining chemical reactions between metal salts and a suitable organic fuel, such as citric acid, urea, hydrazides, malonic acid dihydrazide, tetra formal tris azine, etc. Since most of the heat required for the synthesis is supplied by the reaction itself, the mixture of the reactants only needs to be heated to temperature that is significantly lower than the actual phase formation temperature. The energy expense involved is therefore limited.

2. Experimental procedure

2.1. Preparation of BiVO_4 crystallites

While previous attempts to fabricate BiVO_4 crystallites were carried out using citric acid or urea as fuels, we chose citric acid and urea as co-fuels. The experimental procedure for preparing BiVO_4 crystallites by the SCS method is schematically shown in Fig. 1. First, $\text{Bi}(\text{NO}_3)_3 \cdot 5\text{H}_2\text{O}$ (Wako, Japan) and the same molar quantity of citric acid (Wako, Japan) were dissolved in a nitric acid aqueous solution (Wako, Japan). After magnetic stirring for 30 min, a transparent solution was formed. $\text{NH}_3 \cdot \text{H}_2\text{O}$ (Shawo, Japan) was then added to this solution to adjust the pH

^{*} Corresponding author. Tel.: +81 3 57063259; fax: +81 3 57063259.
E-mail address: hgjiang@sc.musashi-tech.ac.jp (H.-q. Jiang).

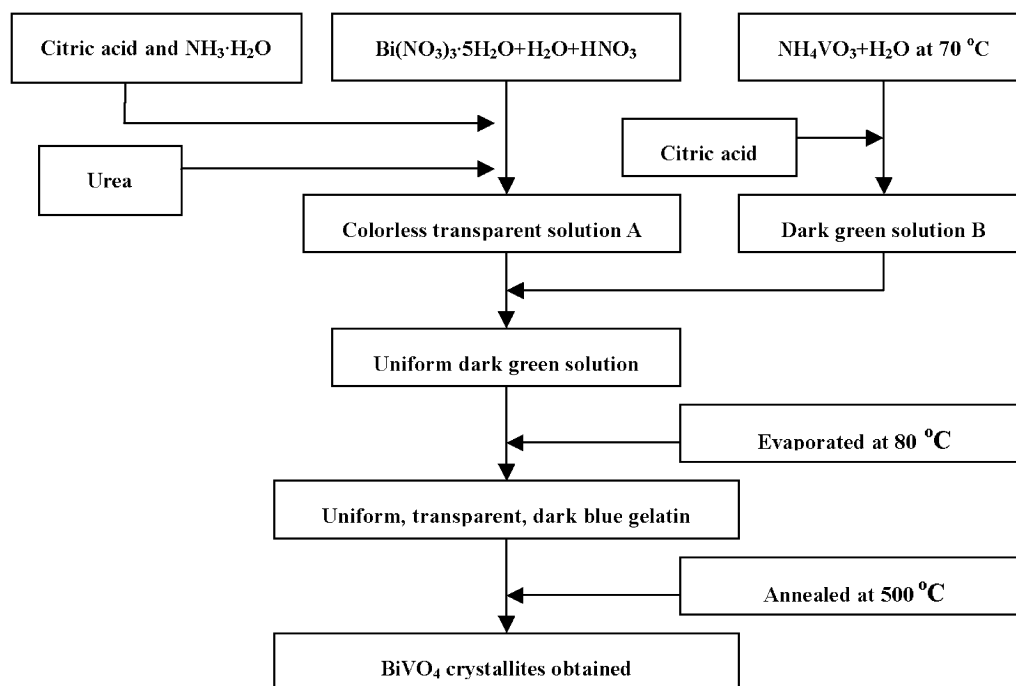


Fig. 1. Schematic diagram for the preparation of BiVO_4 using the solution combustion synthesis method.

value to 7.5. Finally, urea (Wako, Japan) was added to obtain a transparent solution A. Meanwhile, NH_4VO_3 (Wako, Japan) was dissolved in deionized water at 70°C . The same molar quantity of citric acid was added to obtain a dark green solution B. After mixing solutions A and B, a uniform dark green solution was obtained. The mixture thus obtained was evaporated at 80°C in a drying oven for 20 h. Finally, a transparent, uniform, deep blue gelatin is obtained. The BiVO_4 crystallites were synthesized by annealing the obtained gelatins at $480\text{--}500^\circ\text{C}$ in air for different times with a heating rate of $2^\circ\text{C}/\text{min}$ from room temperature to 300°C and $3^\circ\text{C}/\text{min}$ from 300°C to the annealing temperature.

In the process of preparing the gel, citric acid was not only employed as a fuel, but was also applied as a chelating agent. Urea was also used as a fuel at the same time, and it partially decomposed to ammonia and water to maintain the constancy of the pH value of the solution during the evaporation process. Ammonia solution was used to adjust pH value to 7.5. Simultaneously, ammonia solution reacted with the HNO_3 solution to form ammonium nitrate, which could be used as an oxidizer. According to the method proposed by Jain et al.¹⁵ it is possible to calculate the elemental stoichiometric coefficient φ as the ratio between the total valence of the fuel (citric acid and urea) and the total valence of the oxidizers ($\text{Bi}(\text{NO}_3)_3 \cdot 5\text{H}_2\text{O}$, NH_4VO_3 and NH_4NO_3) according to Eq. (1):

$$\varphi = \frac{n[6 \times (+4)_{(\text{C})} + 8 \times (+1)_{(\text{H})} + 7 \times (-2)_{(\text{O})}] + m[(+4)_{(\text{C})} + (-2)_{(\text{O})} + 2 \times 0_{(\text{N})} + 2(+1)_{(\text{H})}]}{x[3(\text{Bi}) + 3(0_{(\text{N})}) + 3 \times (-2)_{(\text{O})}] + y[(+5)_{(\text{V})} + 0_{(\text{N})} + 4 \times 1_{(\text{H})} + 3 \times (-2)_{(\text{O})}] + z[2 \times 0_{(\text{N})} + 4 \times (+1)_{(\text{H})} + 3 \times (-2)_{(\text{O})}]}$$

Here, n , m , x , y and z represent the moles of citric acid, urea, $\text{Bi}(\text{NO}_3)_3 \cdot 5\text{H}_2\text{O}$, NH_4VO_3 and NH_4NO_3 (in this experiment, the theoretical amount of NH_4NO_3 is estimated equal to the amount of HNO_3 , which is about 0.0236 mol), respectively.

According to Eq. (1), $\varphi = 1$, $\varphi < 1$ and $\varphi > 1$ indicate the stoichiometric condition, an oxidant-rich condition and a fuel-rich condition, respectively. In our experiment, a series of BiVO_4 materials were prepared by the SCS method according to different elemental stoichiometric coefficients φ by adjusting the amount of urea (in this experiment, the amount of citric acid in each solution was kept constant).

In this experiment, the monoclinic structure BiVO_4 powders were also prepared through the solid-state reaction (SSR) method by mixing stoichiometric amounts of Bi_2O_3 (Osaka, Japan) and NH_4VO_3 (Wako, Japan). The mixed powders were firstly calcined at 700°C for 20 h. Then the obtained powders were crushed by a mortar. Finally, the monoclinic structure BiVO_4 crystallites were synthesized at 900°C for 10 h.

2.2. Characterizations

The wet gel precursor was characterized by TG–DTA (SII, Seiko instrument, Japan) at a heating rate of $15^\circ\text{C}/\text{min}$ under $150\text{ cm}^3/\text{min}$ flowing air condition. The phase structure of the as-prepared crystallites was investigated through X-ray diffraction (Cu $\text{K}\alpha$, Rint 2000, Rigaku, Co. Ltd., Japan). The diffraction reflection spectra of the as-prepared crystallites were recorded

using a UV–vis spectrophotometer (UV-3100, Shimadzu Corporation, Japan). The specific surface area of BiVO_4 was measured through nitrogen adsorption BET method (Autosorb-1, Quantachrome Instruments, USA). The morphology was observed by

a field emission scanning electron microscope (S-4100, Hitachi Ltd., Japan).

The photocatalytic activities of the samples were evaluated by methylene blue degradation. A 500-W Xe lamp was used as the light source, and the irradiation power was adjusted to 20 mW cm^{-2} through an optometer (P9710, Gigahertz Optik, Germany). First, 5 mg sample was added to the 100 ml of 2 mmol dm^{-3} methylene blue solution. After ultrasonic treatment for 20 min, the solution was stirred for 12 h to reach adsorption–desorption equilibrium. The photocatalytic activity was measured in the range of 320–800 nm by using an optical glass filter. The temperature of the methylene blue solution stirred in a 100 ml beaker was about 25°C . Samples were taken at 20 min intervals and separated by centrifugation. The absorbance of methylene blue was measured by the aforementioned UV–vis spectrophotometer.

3. Results and discussion

3.1. DTA–TG analysis of the precursor gel

Fig. 2 shows the typical thermal behavior of the precursor gel. The DTA curve indicates that there are two endothermic peaks and three exothermic peaks up to 500°C . The broad endothermic peaks from 100°C to 148°C are attributed to the gradual evaporation of free water and absorbed water. The broad endothermic peak from 200°C to 270°C is due to the decomposition of different nitrates and ammonium nitrate, accompanied by significant weight loss. The sharply exothermic peak at 152°C with dramatic weight loss in the TG curve is assigned to the decomposition of urea because the decomposition reaction of urea is exothermic reaction. The sharply exothermic peak at 283°C corresponds to the decomposition and combustion of citrates. The small broad exothermic peak centered at 481°C is due to the complete oxidation of residual carbon in the sample accompanied by approximate 3% weight loss. At the same time, a monoclinic phase structure BiVO_4 crystallites form at this temperature.

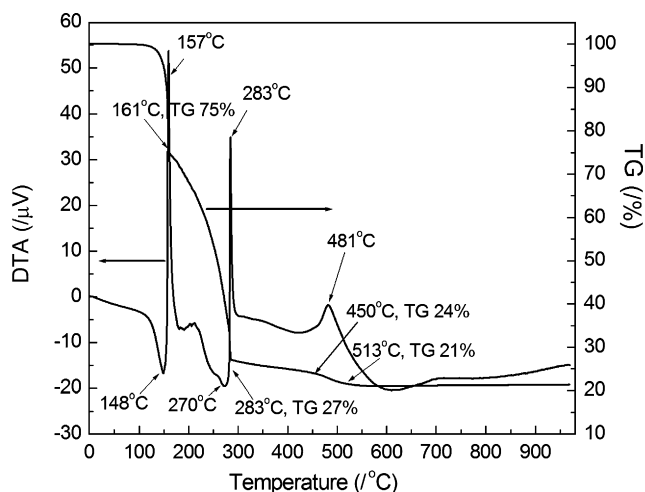


Fig. 2. DTA–TG curves of the BiVO_4 precursor gel.

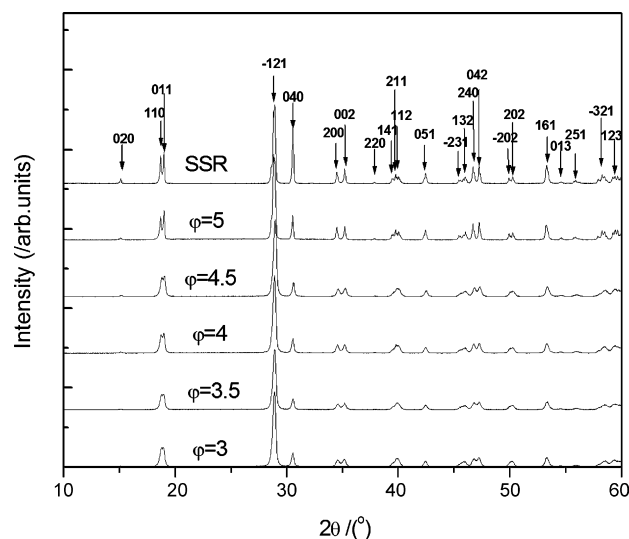


Fig. 3. XRD results for the BiVO_4 crystallites prepared by the SCS method with different values of ϕ ($@ 500^\circ\text{C}$, 4 h, in air) and by the SSR method ($@ 900^\circ\text{C}$, 10 h, in air).

3.2. XRD analysis

The XRD pattern (Fig. 3) shows that all the BiVO_4 crystallites have a monoclinic structure (JSPD file no. 14-688, space group: $I2/a$, $a = 5.195$, $b = 11.701$, $c = 5.092$, $\beta = 90.38$). Multi-peak separation fitting of samples prepared by the SCS method is carried out from 28° to 30° according to $\bar{1}30$, $\bar{1}21$ and 121 diffractive peaks. The results are shown in Fig. 4 and Table 1. It is obvious that the intensity of the diffractive peaks increases with the value of ϕ , indicating an increase in the degree of crystallinity. According to the multi-peaks separation results shown in Table 1, the intensity of the $\bar{1}21$ diffractive peak increases in comparison with $\bar{1}30$ and 121 diffractive peaks, which indicates the growth of BiVO_4 crystallites along the $\bar{1}21$ direction. The Scherer equation is used to calculate the particle sizes according to the FWHM of $\bar{1}21$ diffractive peak. The results indicate that the particle sizes along the $\bar{1}21$ direction increase with the increase of ϕ .

3.3. Characterization of morphology

The morphologies of the BiVO_4 crystallites are shown in Fig. 5. All the samples prepared by the SCS method are spherical-shape. The size of BiVO_4 crystallites is about

Table 1
XRD multi-peaks separation results of the $\bar{1}21$ peak for the BiVO_4 crystallites

ϕ	2θ ($^\circ$)	d -Value	FWHM ($^\circ$)	Intensity	Crystal size ^a (nm)
3	28.85	3.092	0.21	3,538	42
3.5	28.88	3.089	0.21	3,912	40
4	28.85	3.083	0.18	6,626	54
4.5	28.86	3.091	0.18	7,426	54
5	28.81	3.097	0.13	12,816	87

^a Calculated according to the $\bar{1}21$ diffractive peak.

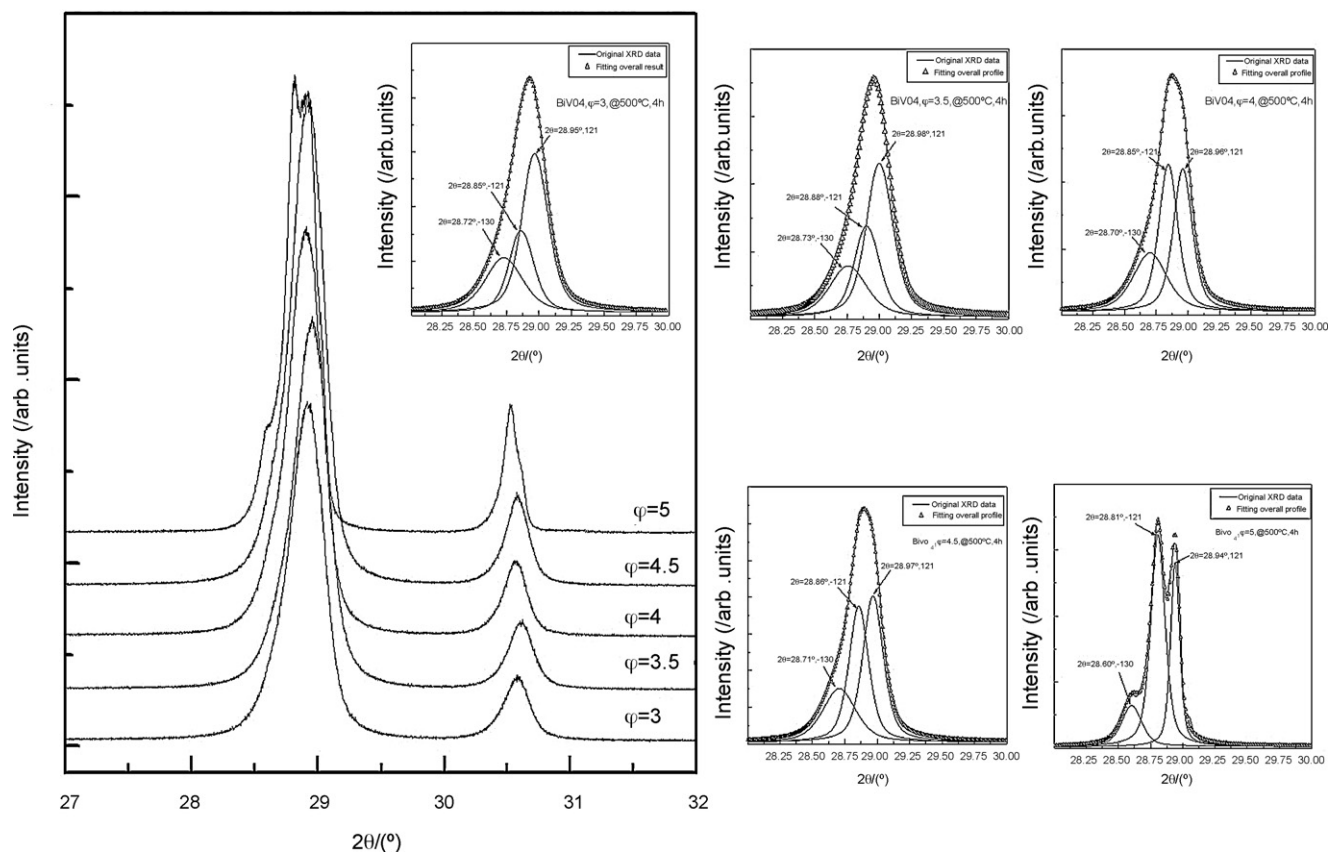


Fig. 4. XRD multi-peaks separation for the BiVO_4 crystallites prepared by the SCS method from 28° to 30° according to the $\bar{1}30$, $\bar{1}21$ and 121 peaks.

400–600 nm. However, BiVO_4 crystallites prepared by SSR method exhibit irregular morphology with particle size about $1.5 \mu\text{m}$.

In the process of the solution combustion technique, it is a significant step to prepare a semi-rigid gelatin with atomic level homogeneity. At pH 7.5, citric acid metal–chelate complexes are formed. During the evaporation of the solvent, the citric acid metal–chelate polymerize to promote uniformity of different metal ions, which can be achieved by encircling stable metal–chelate complexes in a growing polymer net. The randomness of the initial solution will be retained in the final polymeric gelatin because the gelatin consists of many chains twist and tangle together, wherein both cations and solvents are entrapped by steric hindrance. Immobilization of the metal–chelate complexes in such a semi-rigid organic polymer net can reduce segregation of specific metal ions during the decomposition process of the polymer at high temperatures. According to model proposed by Kakihana,¹⁶ with the gradual increase of temperature, a group of polymer long chains break down and change to short polymer chains. Then, short polymer chains twist and tangle together to form spherical aggregated polymer particles. Finally, amounts of short polymer chains form fine crystallites after the polymer chains completely oxidized. At the same time, spherical aggregated polymer particles form the spherical aggregated BiVO_4 crystallites. As a consequence, fine crystallites retain on the surface of BiVO_4 crystallites and form a rough surface.

In Fig. 5, the sample with $\varphi=5$ has a relatively smooth surface. In the SCS method, the maximum temperature of the combustion reaction depends on fuels and the amounts of fuels in the combustion reaction.¹⁴ With the increase of amounts of fuels, the maximum of temperature increased. The sample with $\varphi=5$ can reach to relatively high temperature during the annealing process, which can promote the growth of BiVO_4 crystallites and decrease the roughness of surface.

It can also be observed that all the samples prepared by the SCS method have a similar aggregate particle size, which is unrelated to the φ value, temperature or annealing time. It is our understanding that the aggregate particle size is dependent on the concentration of citric acid in the solution during the evaporation of the solution and the decomposition of the polymerized metal–citrate long chains. At low temperatures, the long chain metal–citrate polymer break down to short chains and aggregate together to form the aggregated polymer particles, which means that the aggregate particle size is decided at a relatively low temperature.

3.4. BET specific surface area

Table 2 shows the specific surface area of BiVO_4 measured by nitrogen adsorption BET method. The BET results indicate that the specific surface area of BiVO_4 crystallites increases slightly with the φ value when the φ value is less than 4. When the φ value is more than 4, the specific surface area of BiVO_4

crystallites gradually decrease with the φ value. At $\varphi=5$, BET specific surface area of BiVO_4 crystallites is $1.76 \text{ m}^2 \text{ g}^{-1}$, which is about 2.4 times than that of BiVO_4 crystallites prepared by the SSR method.

3.5. UV–vis diffusion reflectance spectra

The color of the BiVO_4 crystallites is vivid yellow. Fig. 6 shows the UV–vis diffuse reflection spectra (DRS) of the BiVO_4

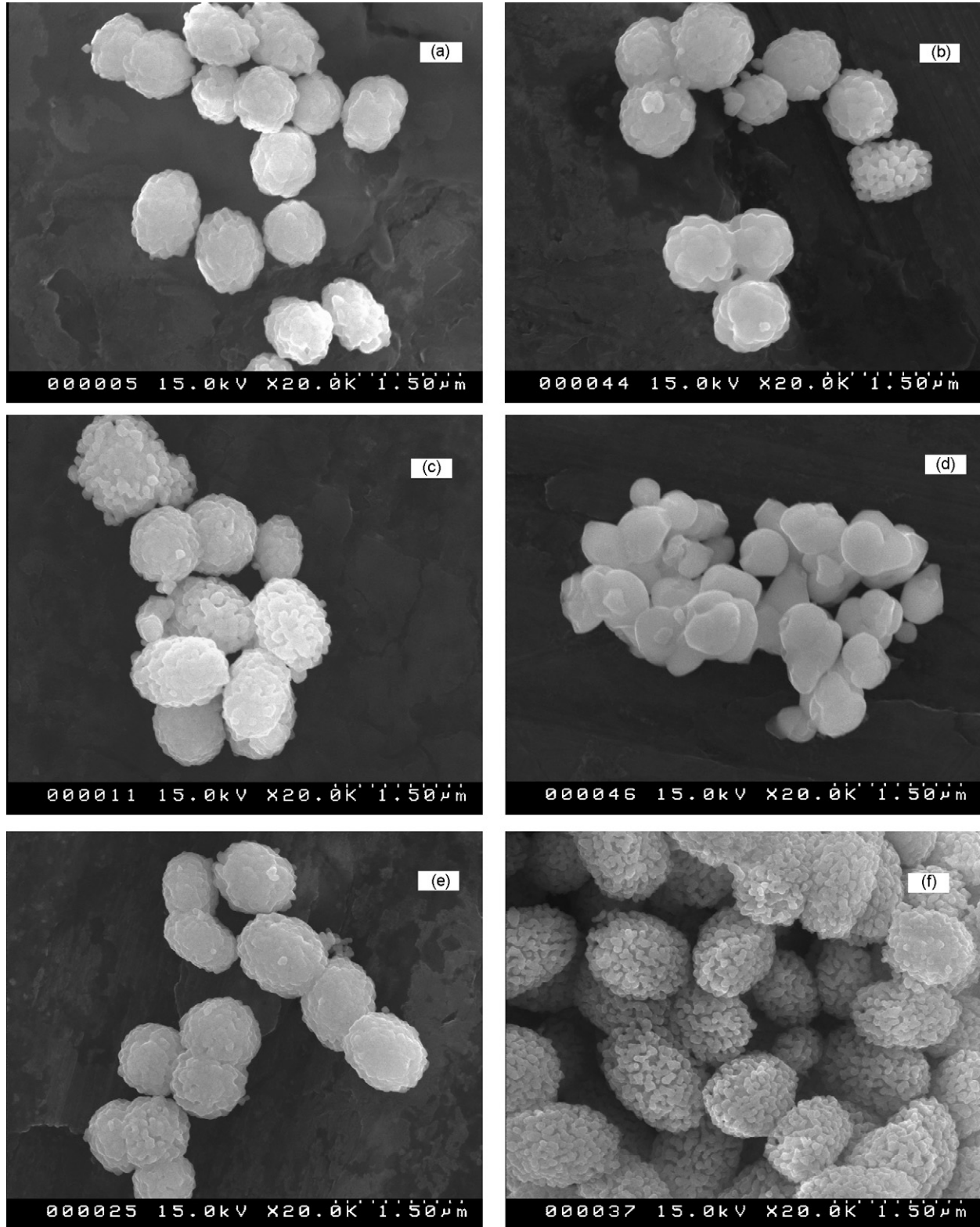


Fig. 5. FE-SEM micrograph of the BiVO_4 crystallites: (a) $\varphi=3$, 500°C , 4 h; (b) $\varphi=4$, 500°C , 4 h; (c) $\varphi=4.5$, 500°C , 4 h; (d) $\varphi=5$, 500°C , 4 h; (e) $\varphi=3.5$, 500°C , 1 h; (f) $\varphi=3.5$, 500°C , 0.2 h; (g) $\varphi=3.5$, 490°C , 1 h; (h) $\varphi=3.5$, 510°C , 1 h; (i) SSR, 900°C , 10 h.

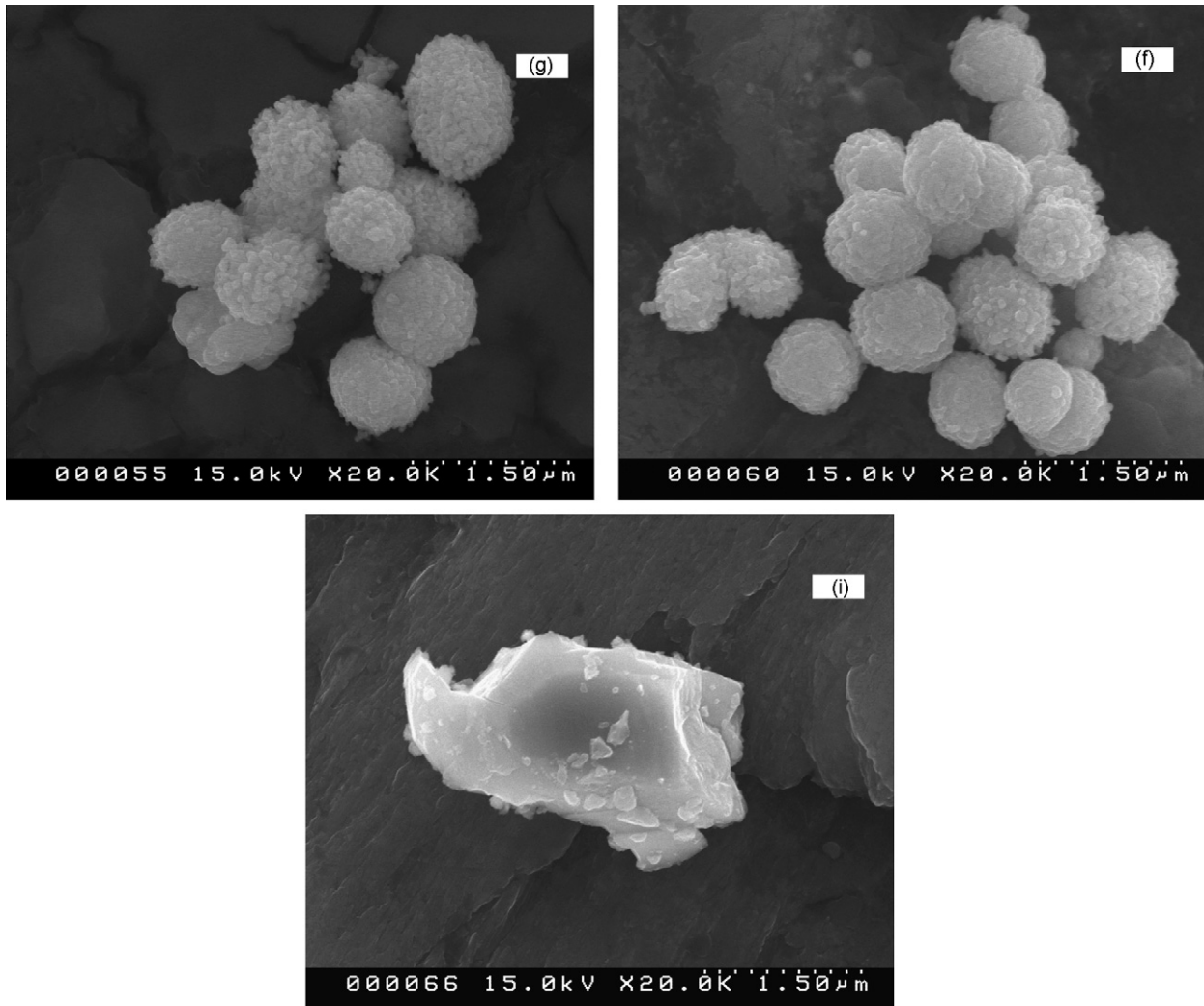
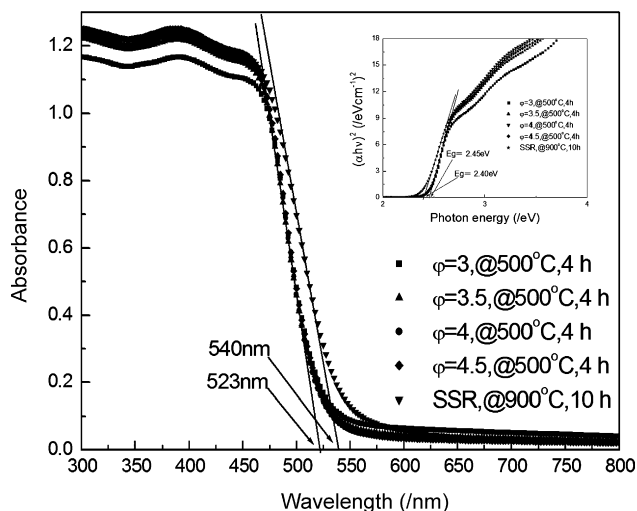


Fig. 5. (Continued).

Fig. 6. UV-vis diffusion reflectance spectra of the BiVO_4 crystallites. The inset shows the relationship between $(\alpha h\nu)^2$ and the photon energy.

crystallites. The relationship between absorbance and incident photon energy $h\nu$ is described in Eq. (2) for direct electron transition:

$$(\alpha h\nu) = A(h\nu - E_g)^{1/2} \quad (2)$$

where A , E_g and $h\nu$ represent a constant, direct band gap energy and incident photon energy, respectively. The band gap absorption edges of the BiVO_4 crystallites prepared by the SCS method and the SSR method are determined to be 523 nm and 540 nm, corresponding to the band gap energies of 2.45 eV and 2.40 eV (shown in the inset in Fig. 6), respectively, which are

Table 2
BET specific surface area of BiVO_4 crystallites

Sample	BET specific surface area ($\text{m}^2 \text{g}^{-1}$)
$\varphi = 3$	2.36
$\varphi = 3.5$	2.49
$\varphi = 4$	2.72
$\varphi = 4.5$	2.62
$\varphi = 5$	1.76
SSR	0.74

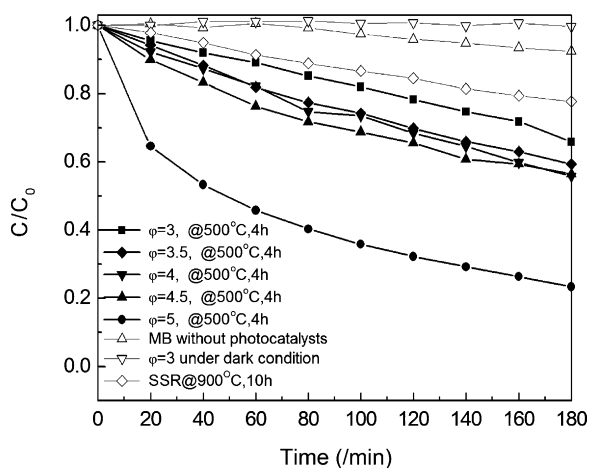


Fig. 7. Photocatalytic activity of BiVO₄ crystallites with different ϕ values.

the directly allowed optical transition. This is very consistent with the reported band gap value of the monoclinic BiVO₄.^{9,10} The obvious blue shift of band gap absorption edges for BiVO₄ crystallites prepared by the SCS method comparing to the SSR method is observed, which is likely ascribed to quantum size effect caused by the difference of crystal size. According to the results of XRD and FE-SEM, the crystal size of BiVO₄ particles prepared by the SCS method is far less than that of BiVO₄ prepared by the SSR method. No obvious shift in the band gap absorption edge was observed among the samples prepared by the SCS method at the different ϕ values.

3.6. Photocatalytic activity for degradation of methylene blue solution

To determine the photocatalytic activity of the prepared BiVO₄ photocatalyst, an experiment was carried out using a methylene blue solution as the probe material with an initial concentration of 2 mmol dm⁻³. The band edge position of the conduction band and the valance band of a semiconductor can be determined using a simple approach.^{17,18} The conduction band edge of a semiconductor at the point of zero charge (pH_{ZPC}) can be predicted by Eq. (3):

$$E_{CB}^0 = X - E^C - \frac{1}{2}E_g \quad (3)$$

Here, X is the absolute electronegativity of the semiconductor, expressed as the geometric mean of the absolute electronegativity of the constituent atoms, which is defined as the arithmetic mean of the atomic electron affinity and the first ionization energy (for BiVO₄, X is 6.035 eV¹⁹). E^C is the energy of free electrons on the hydrogen scale (~ 4.5 eV). E_g is the band gap of the semiconductor. According to Eq. (3), the positions of the conduction band and the valance band are 0.31 eV and 2.76 eV, respectively. After reaction with water, the holes photo-generated in the valance band can produce OH, O₂⁻, H₂O₂ and O₂, which can effectively promote the degradation of the methylene blue solution.²⁰ The relation between C/C_0 and the reaction time is shown in Fig. 7. It is obvious that the photocatalytic activity of the samples increase with the increase of ϕ value. When the

ϕ value is 5, the photocatalytic activity sharply increases, comparing to the other samples. From Fig. 5, it can be observed that the surface of the sample with $\phi = 5$ is smooth without a rough morphology, which suggests an increase in the degree of crystallinity. The XRD results also reveal that the relative intensity of $\bar{1}21$ diffractive peak of the sample with $\phi = 5$ increases.

As a direct electron transition semiconductor, the monoclinic BiVO₄ crystal is excited by the incident photons with energy equal to or greater than their band energy level. The electrons receive energy from the photons and are thus promoted from the valence band to the conduction band, if the energy gained is higher than the band gap energy level. Electrons and holes that migrate to the surface of the semiconductor without recombination can respectively reduce or oxidize the reactants adsorbed by the semiconductor. In the process of migration to the surface of the semiconductor, the mobility of the photo-generated charge carriers is a key factor. If there are many crystal boundaries and defects in the semiconductor interior, which play the role of recombination centers for electrons and holes, this will hinder the diffusion of electrons and holes from the interior to the surface of the semiconductor. The photo-generated electrons and holes could recombine in the bulk or on the surface of the semi-

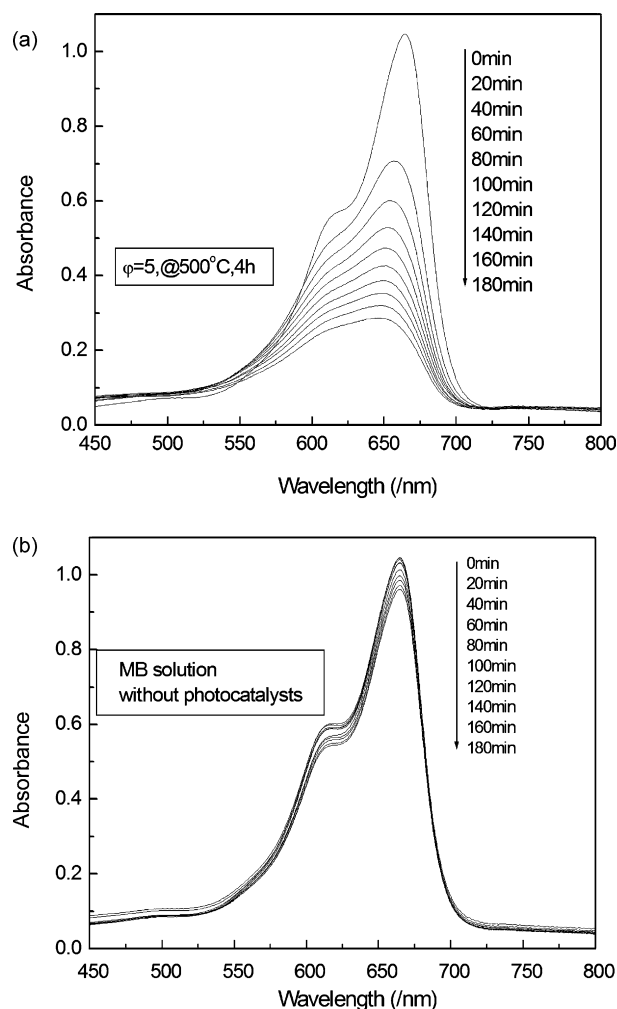


Fig. 8. Photodegradation process of methylene blue: (a) with BiVO₄ crystallites; (b) without BiVO₄ crystallites.

conductor within a very short time, releasing energy in the form of heat or photons. The photocatalytic activity decreases with fewer electrons and holes on the surface. For the sample with $\varphi = 5$, greater amounts of fuels can promote the degree of crystallinity and reduce the amounts of defects in the BiVO_4 crystal. Consequently, the photocatalytic activity increases. However, the sample prepared by the SSR method exhibits the worse photoactivities which can be ascribed to the increase of particle size, relatively low specific surface area and serious aggregation. Fig. 8 shows the photodegradation process of methylene blue over sample of $\varphi = 5$ and photolysis process of methylene blue without BiVO_4 photocatalysts.

4. Conclusions

Spherical and irregular shaped monoclinic BiVO_4 crystallites were prepared through the SCS method and the SSR method, respectively. The aggregate particle size of the BiVO_4 crystallites prepared by the SCS method is about 400–600 nm. The particle size of the BiVO_4 crystallites prepared by the SSR method is about 1.5 μm . With the increase of φ value, the degree of crystallinity of the BiVO_4 crystallites increases. When φ value is 5, the photocatalytic activity sharply increases. The value of C/C_0 is about 0.24 after 180 min and is about 3.5 times that of BiVO_4 prepared by the SSR method, which can be attributed to the increase in the crystallinity and a decrease in crystal defects. The band gap absorption edges of the BiVO_4 crystallites prepared by the SCS method and the SSR method are determined to be 523 nm and 540 nm, corresponding to the band gap energies of 2.45 eV and 2.40 eV, respectively.

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